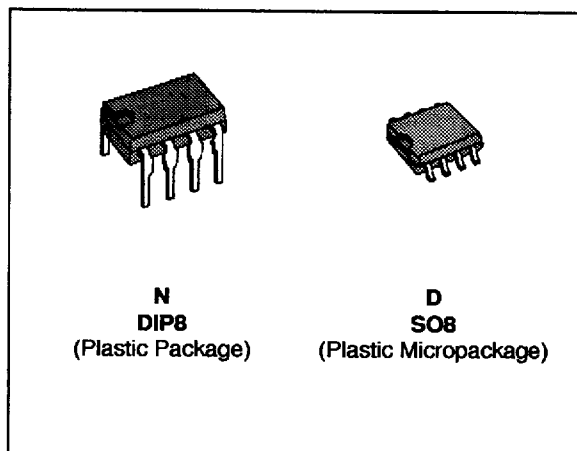


PROGRAMMABLE LOW POWER SINGLE OPERATIONAL AMPLIFIERS

- MICROPOWER OPERATION
- NO FREQUENCY COMPENSATION REQUIRED
- WIDE PROGRAMMING RANGE
- HIGH SLEW RATE
- SHORT-CIRCUIT PROTECTION
- PROGRAMMABLE SINGLE OP-AMPS



ORDER CODES

Part Number	Temperature Range	Package	
		N	D
UA776C	0°C, +70°C	•	•
UA776I	-40°C, +105°C	•	•
UA776M	-55°C, +125°C	•	•

Example : UA776CN, UA776CD

776-01 TBL

DESCRIPTION

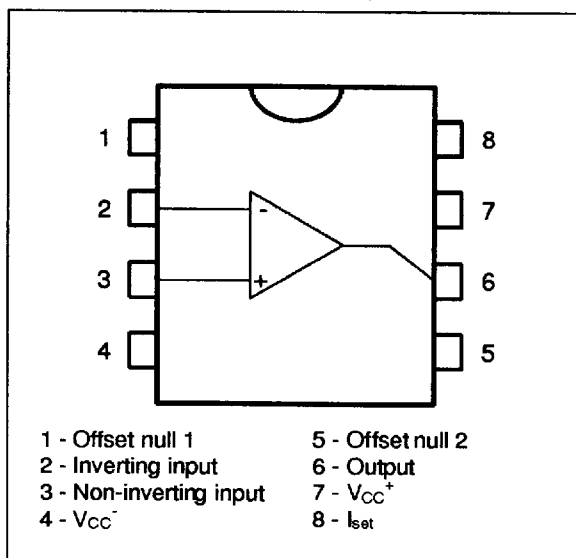
The UA776 programmable operational amplifier is characterized by, low supply current and low input noise over a wide range of operating supply voltages.

Coupled with programmable electrical characteristics, it is an extremely versatile amplifier for use in high accuracy, low power consumption analog applications.

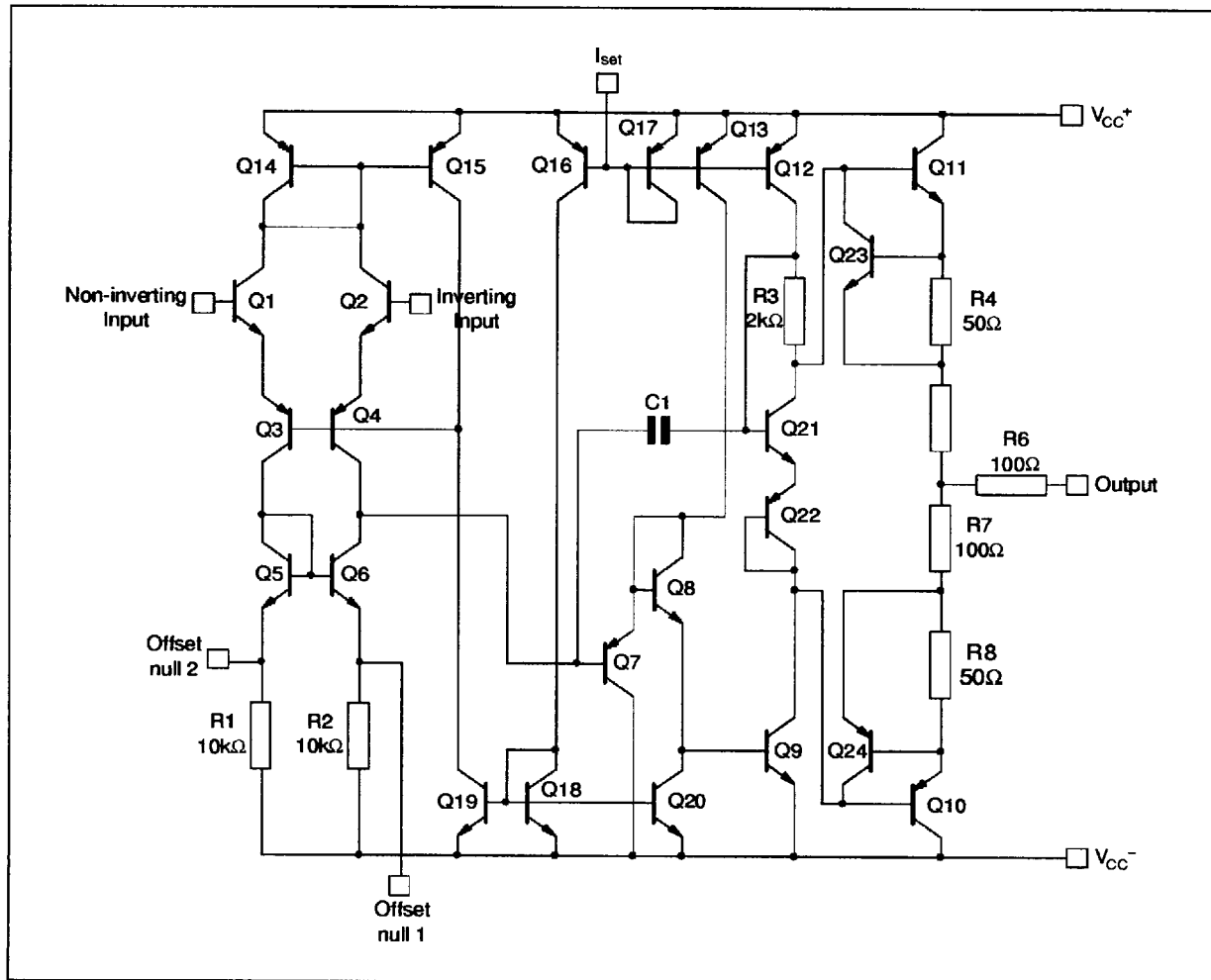
Input noise voltage and current, power consumption, and input current can be optimized by a single resistor or current source that sets the chip quiescent current for nano-watt power consumption or for characteristics similar to the UA741.

Internal frequency compensation, absence of latch up, high slew rate and short-circuit protection assure ease of use in long time integrators, active filters, and sample and hold circuits.

PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	UA776M	UA776I	UA776C	Unit
V_{CC}	Supply Voltage	± 18	± 18	± 18	V
V_i	Input Voltage - (note 1)	± 15	± 15	± 15	V
V_{id}	Differential Input Voltage	± 30	± 30	± 30	V
P_{tot}	Power Dissipation	500	310	310	mW
	Output Short-circuit Duration	Infinite			
T_{oper}	Operating Free Air Temperature Range	-55 to +125	-40 to +105	0 to +70	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	-65 to +150	-65 to +150	-65 to +150	$^{\circ}\text{C}$

Note : 1. For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

ELECTRICAL CHARACTERISTICS $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	$I_{set} = 1.5\mu A$			$I_{set} = 15\mu A$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{io}	Input Offset Voltage $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		2	5 6		2	5 6	mV
I_{io}	Input Offset Current $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		0.7	3 10		2	15 40	nA
I_{ib}	Input Bias Current $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		2 2	7.5 10 20		15 15	50 50 100	nA
A_{vd}	Large Signal Voltage Gain ($V_o = \pm 10V$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$							V/mV
	$R_L = 5k\Omega$ $R_L = 75k\Omega$ $R_L = 75k\Omega$ $R_L = 5k\Omega$	200 100	400		100 75	400		
SVR	Supply Voltage Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	77 77	92		77 77	92		dB
I_{CC}	Supply Current - (no load) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	25 30		160	180 200	μA
V_{icm}	Input Common Mode Voltage Range	± 10			± 10			V
CMR	Common Mode Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 70	90		70 70	90		dB
I_{os}	Output Short-circuit Current	0.5	3	15	6	12	30	mA
$\pm V_{OPP}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$							V
	$R_L = 5k\Omega$ $R_L = 75k\Omega$ $R_L = 75k\Omega$	12 10	14		10 10	13		
V_{ior}	Offset Voltage Adjustment Range		9			18		mV
SR	Slew Rate ($V_i = \pm 10V$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$	0.01	0.1		0.2	0.8		V/ μs
t_r	Rise Time ($V_i = \pm 20mV$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$		1.6			0.35		μs
K_{OV}	Overshoot ($V_i = \pm 20mV$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$		0			10		%
R_i	Input Resistance		50			5		M Ω
C_{id}	Differential Input Capacitance		2			2		pF
R_o	Output Resistance		5			1		k Ω
GBP	Gain Bandwidth Product ($T_{amb} = 25^{\circ}C$, $C_L = 100pF$) $f = 100kHz$ $f = 10kHz$							MHz
	$R_L = 5k\Omega$ $R_L = 75k\Omega$	0.03	0.1		0.4	0.7		
THD	Total Harmonic Distortion ($f = 1kHz$, $A_v = 20dB$, $V_o = 2V_{PP}$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$) $R_L = 5k\Omega$ $R_L = 75k\Omega$		0.8			0.025		%
e_n	Equivalent Input Noise Voltage ($f = 1kHz$, $R_s = 100\Omega$)		40			20		$\frac{nV}{\sqrt{Hz}}$

776-03.TBL

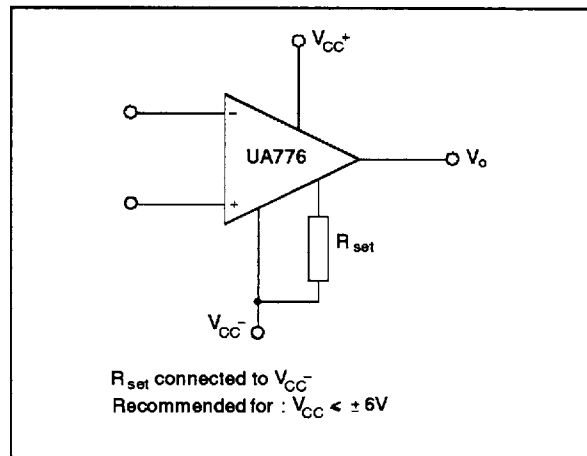
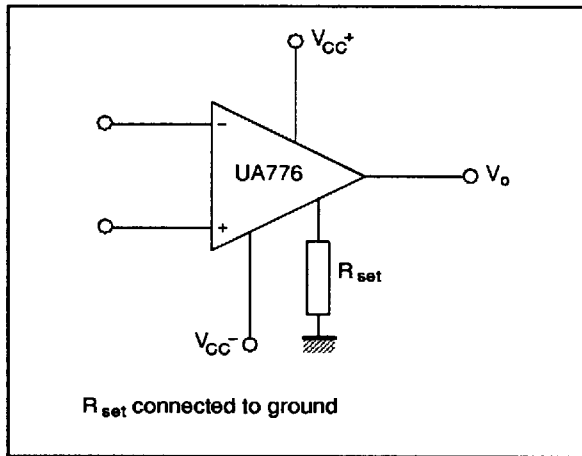
ELECTRICAL CHARACTERISTICS
 $V_{CC} = \pm 3V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	$I_{set} = 1.5\mu A$			$I_{set} = 15\mu A$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{io}	Input Offset Voltage $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		2	5 6		2	5 6	mV
I_{io}	Input Offset Current $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		0.7	3 10		2	15 40	nA
I_{ib}	Input Bias Current $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		2 2	7 10 20		15 15	50 50 100	nA
A_{vd}	Large Signal Voltage Gain ($V_o = \pm 1V$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	200		50 25	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	77 77	92		77 77	92		dB
I_{CC}	Supply Current, no load $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		13	20 25		130	160 180	μA
V_{icm}	Input Common Mode Voltage Range	± 1			± 1			V
CMR	Common Mode Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 70	90		70 70	90		dB
I_{os}	Output Short-circuit Current	0.5	3	15	2	5	20	mA
$\pm V_{OPP}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	2 2	2.4		2 1.9 2 1.9	2.4 2.1		V
V_{ior}	Offset Voltage Adjustment Range		9			18		mV
SR	Slew Rate ($V_i = \pm 1V$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$		0.03			0.35		V/ μs
t_r	Rise Time ($V_i = \pm 20mV$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$		3			0.6		μs
KOV	Overshoot ($V_i = \pm 20mV$, $C_L = 100pF$, unity gain) $R_L = 5k\Omega$ $R_L = 75k\Omega$		0			5		%
R_i	Input Resistance		50			5		M Ω
C_{id}	Differential Input Capacitance		2			2		pF
R_o	Output Resistance		5			1		k Ω
GBP	Gain Bandwidth Product ($T_{amb} = 25^{\circ}C$, $C_L = 100pF$) $f = 100kHz$ $f = 10kHz$		0.075			0.5		MHz
THD	Total Harmonic Distortion ($f = 1kHz$, $A_v = 20dB$, $V_o = 1V_{PP}$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$) $R_L = 5k\Omega$ $R_L = 75k\Omega$		1			0.03		%
e_n	Equivalent Input Noise Voltage ($f = 1kHz$, $R_s = 100\Omega$)		20			20		$\frac{nV}{\sqrt{Hz}}$

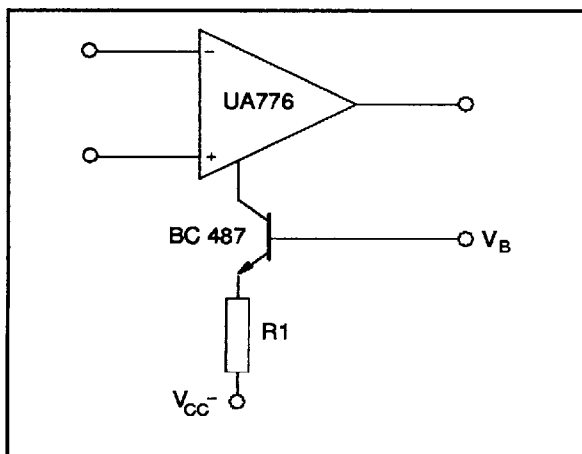
776-04 TBL

BIASING CIRCUITS

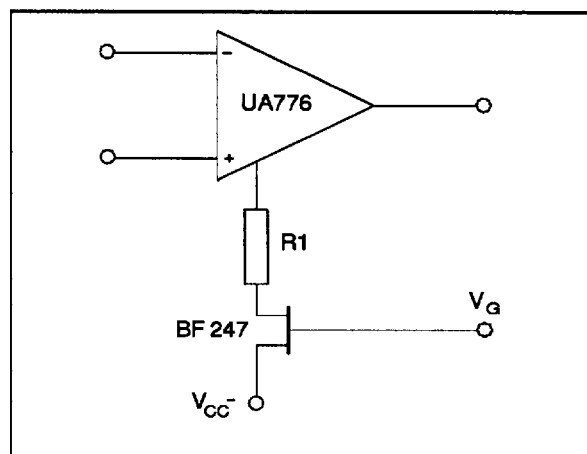
RESISTOR BIASING



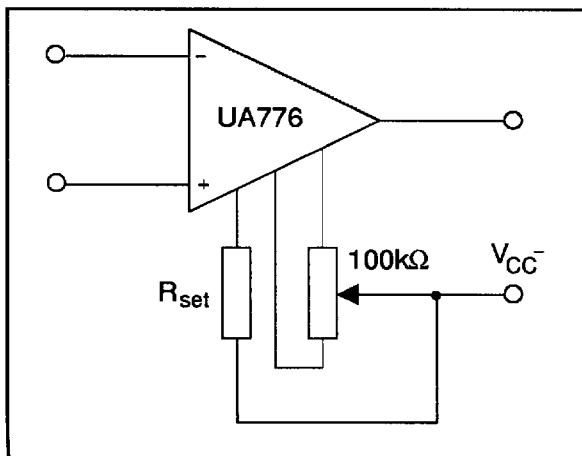
TRANSISTOR CURRENT SOURCE BIASING



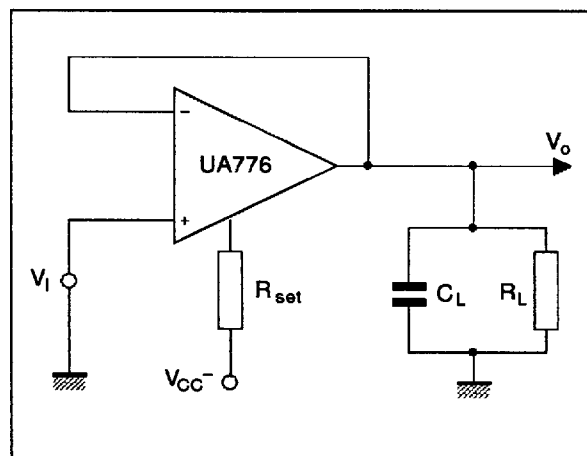
FET CURRENT SOURCE BIASING



OFFSET VOLTAGE NULL CIRCUIT

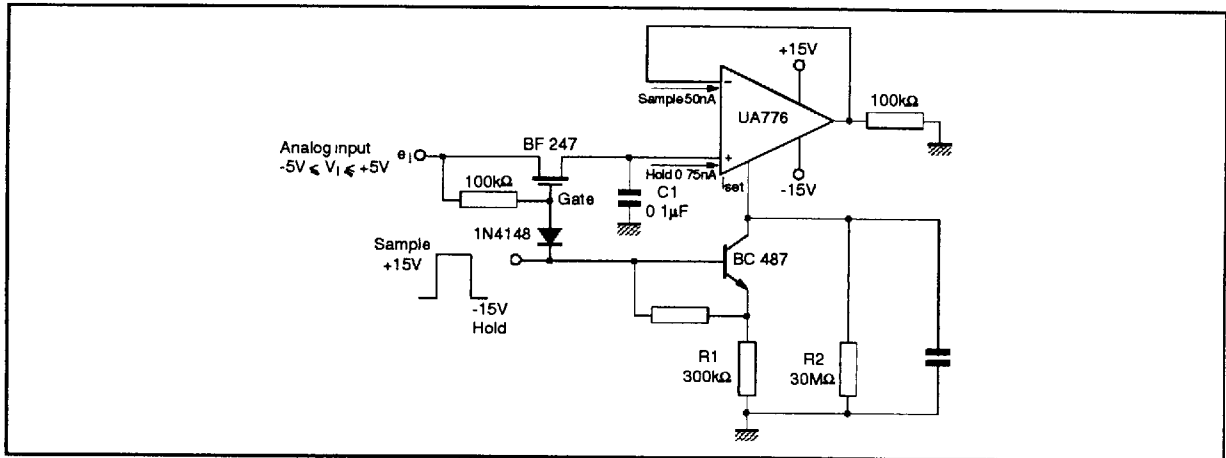


TRANSIENT RESPONSE TIME TEST CIRCUIT



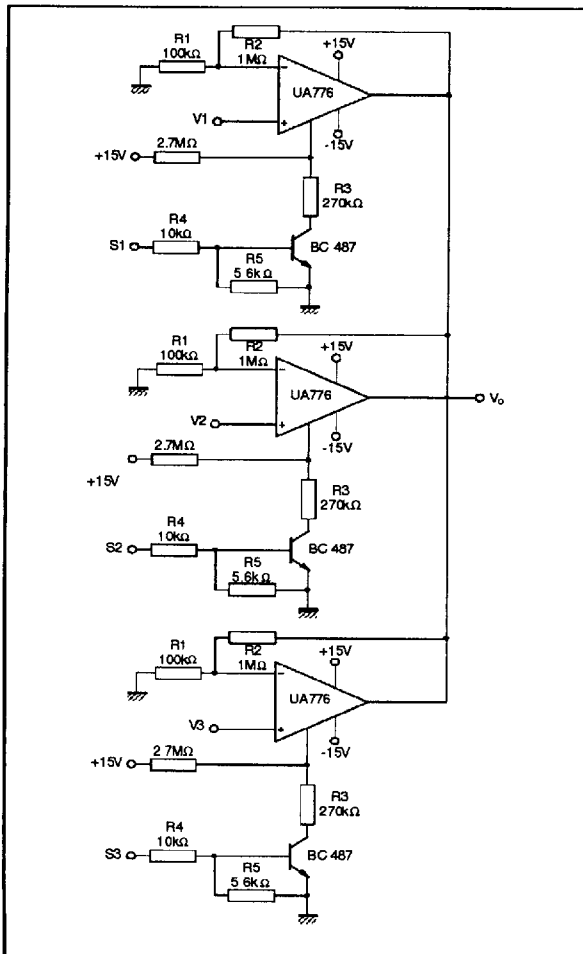
TYPICAL APPLICATIONS

HIGH ACCURACY SAMPLE AND HOLD



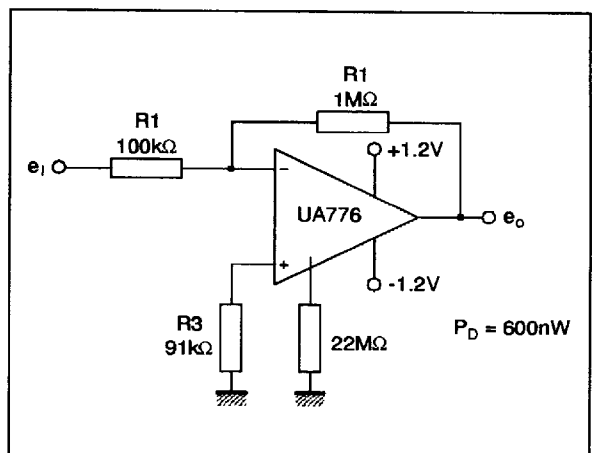
776-10 EPS

MULTIPLEXING AND SIGNAL CONDITIONING WITHOUT FETs



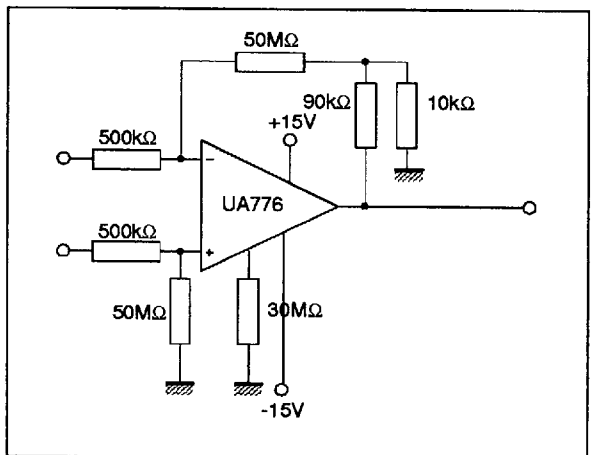
776-11 EPS

NANO-WATT AMPLIFIER

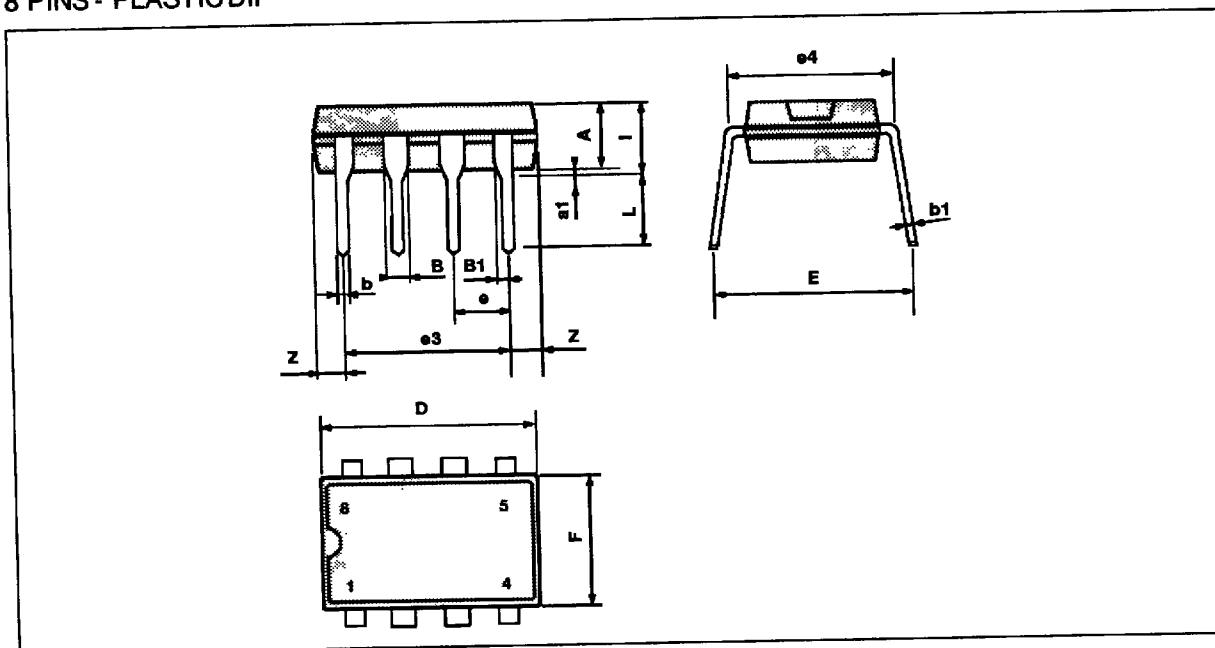


776-12 EPS

HIGH INPUT IMPEDANCE AMPLIFIER



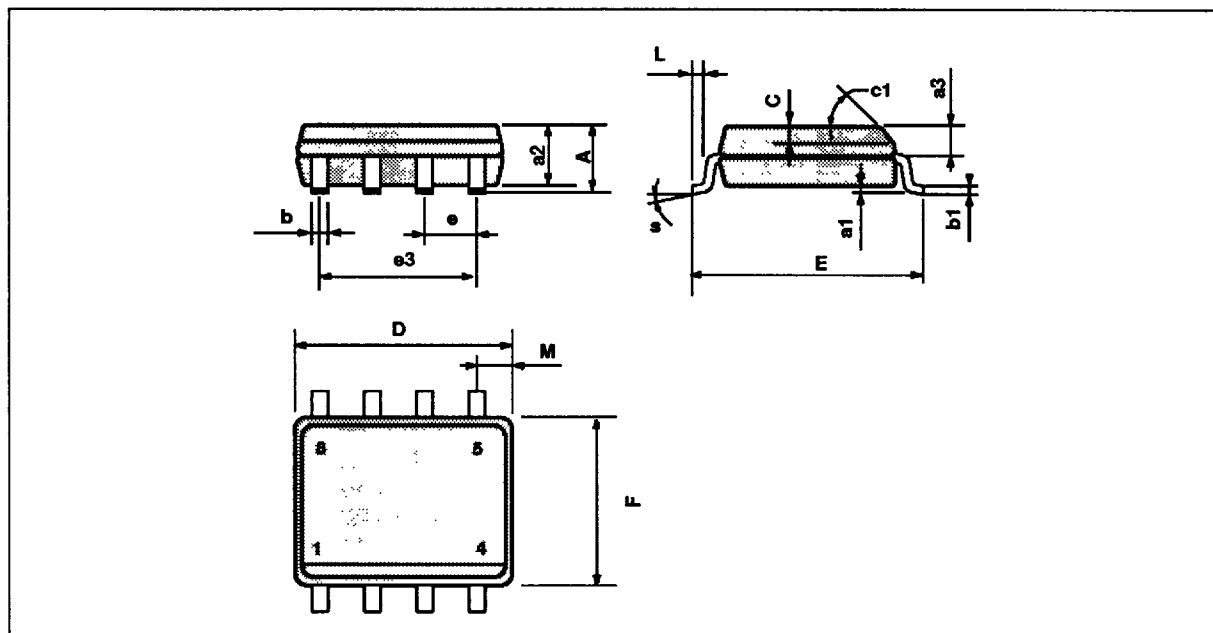
776-13 EPS

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP


PM-DIP8 EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8 TBL

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)


PM-S06 EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

SO8 TBL

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